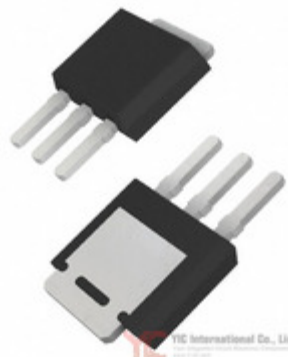
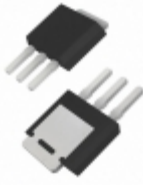

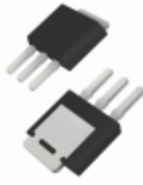
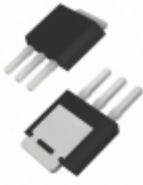

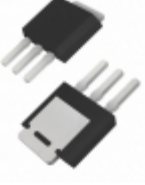
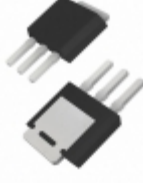
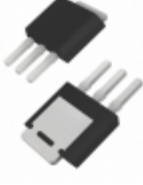
	<h2>AOI11S60</h2>
	<p>Hersteller-Teilenummer: AOI11S60</p> <p>Hersteller / Marke: Alpha and Omega Semiconductor, Inc.</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 11A TO251A</p> <p>Datenblätter: 1.AOI11S60.pdf 2.AOI11S60.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 6300 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	AOI11S60
Hersteller	Alpha and Omega Semiconductor, Inc.
Beschreibung	MOSFET N-CH 600V 11A TO251A
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	6300 pcs Stock
Serie	aMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Stub Leads, IPak
Supplier Device-Gehäuse	TO-251A
Verlustleistung (max)	208W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	11A (Tc)
Rds On (Max) @ Id, Vgs	399 mOhm @ 3.8A, 10V
VGS (th) (Max) @ Id	4.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	11nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	545pF @ 100V
Verpackung	Tube

AOI11S60 ist neu im Original, Suche AOI11S60 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie AOI11S60 Alpha and Omega Semiconductor, Inc. mit Garantie und Vertrauen. Anfrage AOI11S60: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>AOI2610 Alpha and Omega Semiconductor, Inc. MOSFET NCH 60V 46A TO251A</p>	 <p>AOI206_002 Alpha and Omega Semiconductor, Inc. MOSFET N-CH 30V 18A TO251A</p>	 <p>AOI2610E Alpha and Omega Semiconductor, Inc. MOSFET N-CH 60V 46A TO251A</p>	 <p>AOI1N60 Alpha and Omega Semiconductor, Inc. MOSFET N-CH 600V 1.3A TO251A</p>
 <p>AOI206 AOS AOI206 AOS</p>	 <p>AOI208 Alpha and Omega Semiconductor, Inc. MOSFET N-CH 30V 18A TO251A</p>	 <p>AOI1N60L Alpha and Omega Semiconductor, Inc. MOSFET N-CH 600V 1.3A TO251A</p>	 <p>AOI2210 Alpha and Omega Semiconductor, Inc. MOSFET N-CH</p>

heiße Teile

Mehr

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ADR02BRZ	AOI1N60L	AOI2610E	AOI2N60A	AOI2NL60
AOI472AL	AOI4T60P	AOI4TL60	APTGF50X60P2	AT93C46A-10SU-2.7A
AZ431LBRTR-E1	BZM55C8V2	C1005X8R1H332K050BE	CDCE906R004PWR	CGRMT4003-HF
DM74ALS541SJX	F40163BPC	FQP2N60B	ILD213E2	IRFR9N20DPBF
KM416C256BJ-6	KSB23020	LT3663EDCB#TRPBF	M0130RL220	M505063V
MAP3205BE	MAX803LEXR+T	MAX8527EUDIF	MAZ31000L3HT	MMBZ5239BLT1
OPB609GU	PIC12LF1552-I/SN	PIC16LF877A-I/ML	R6220830PSOO	REF193GPZ
RM50C1A-12F	SC0037S00FEL	SC809-2.63V	SG3525AP013TR	SP487ECT-L/TR
TPS56221DQPR	U4082B-MFLG	VI-223-EY	VI-244-CX	VI-261-CU-08

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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